

Is Now Part of



ON Semiconductor®

To learn more about ON Semiconductor, please visit our website at <u>www.onsemi.com</u>

Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (_), the underscore (_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.onsemi.com. Please email any questions regarding the system integration to Fairchild_questions@onsemi.com.

ON Semiconductor and the ON Semiconductor logo are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or unavteries, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out or i, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that ON Semiconductor was negligent regarding the design or manufacture of the part. ON Semiconductor and is officers, employees, uniotificated use, even if such claim any manner.



FDP8030L/FDB8030L

N-Channel Logic Level PowerTrench[®] MOSFET

General Description

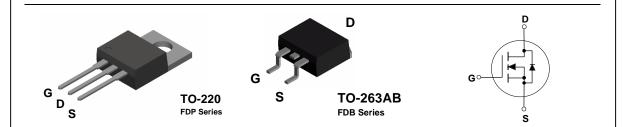
This N-Channel Logic level MOSFET has been designed specifically to improve the overall efficiency of DC/DC converters using either synchronous or conventional switching PWM controllers.

These MOSFETS feature faster switching and lower gate charge than other MOSFETS with comparable $R_{\text{DS}(\text{on})}$ specifications.

The result is a MOSFET that is easy and safer to drive (even at very high frequencies), and DC/DC power supply designs with higher overall efficiency.

Features

- 80 A, 30 V. $R_{DS(ON)} = 0.0035 \ \Omega \ @ \ V_{GS} = 10 \ V$ $R_{DS(ON)} = 0.0045 \ \Omega \ @ \ V_{GS} = 4.5 \ V$
- Critical DC electrical parameters specified at elevated temperature
- Rugged internal source-drain diode can eliminate the need for an external Zener diode transient suppressor
- High performance trench technology for extremely low R_{DS(ON)}
- 175°C maximum junction temperature rating



Absolute Maximum Ratings TA=25°C unless otherwise noted

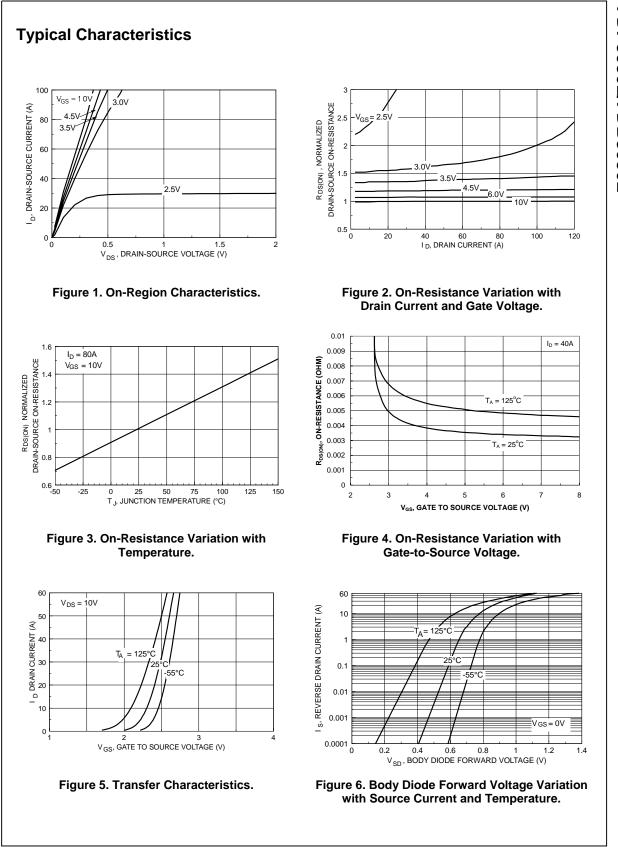
Symbol	Parameter	Ratings	Units
V _{DSS}	Drain-Source Voltage	30	V
V _{GSS}	Gate-Source Voltage	±20	V
I _D	Drain Current – Continuous (Note	1) 80	A
	– Pulsed (Note	1) 300	
PD	Total Power Dissipation @ $T_c = 25^{\circ}C$	187	W
	Derate above 25°	C 1.25	W°C
T _J , T _{STG}	Operating and Storage Junction Temperature Rang	e -65 to +175	°C
TL	Maximum lead temperature for soldering purposes, 1/8" from case for 5 seconds	275	°C
Therma	I Characteristics		
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case	0.8	°C/W
R _{eJA}	Thermal Resistance, Junction-to-Ambient	62.5	°C/W

©2012 Fairchild Semiconductor Corporation

May 2013

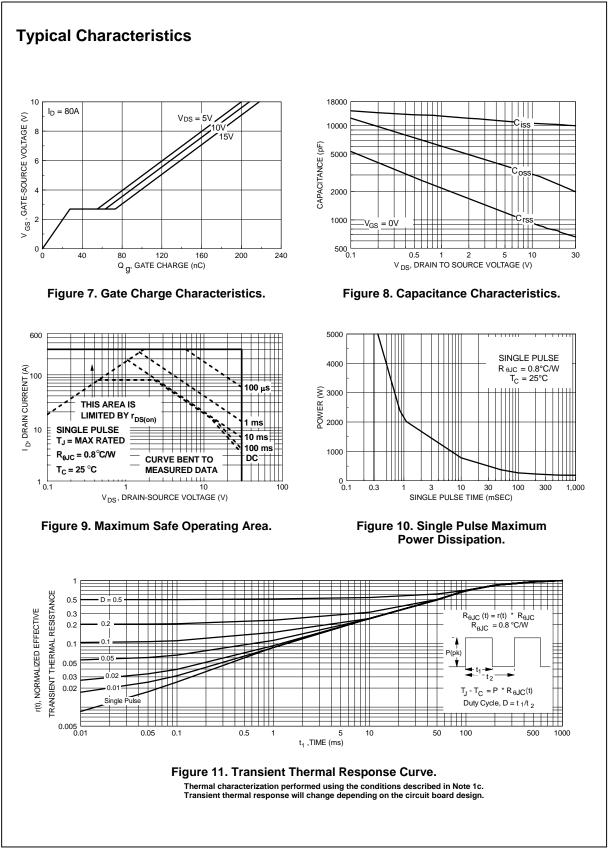
	Deveneter	Test Conditions	N/1:10	T	Max	11
Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Drain-So	purce Avalanche Ratings (Note					
W _{DSS}	Single Pulse Drain-Source Avalanche Energy	$V_{DD} = 20 V, I_D = 80 A$			1500	mJ
AR	Maximum Drain-Source Avalanche Current				80	A
Off Char	acteristics					
BV _{DSS}	Drain–Source Breakdown Voltage	V _{GS} = 0 V, I _D = 250 μA	30			V
<u>ΔBV_{DSS}</u> ΔT _J	Breakdown Voltage Temperature Coefficient	$I_D = 250 \ \mu\text{A}$, Referenced to 25°C		23		mV/°C
IDSS	Zero Gate Voltage Drain Current	$V_{\text{DS}} = 24 \text{ V}, \qquad V_{\text{GS}} = 0 \text{ V}$			10	μA
IGSSF	Gate–Body Leakage, Forward	$V_{GS} = 20 \text{ V}, \qquad V_{DS} = 0 \text{ V}$			100	nA
	Gate-Body Leakage, Reverse	$V_{GS} = -20 V$ $V_{DS} = 0 V$			-100	nA
On Char	acteristics (Note 2)					
V _{GS(th)}	Gate Threshold Voltage	V _{DS} = V _{GS} , I _D = 250 μA	1	1.5	2	V
<u>ΔVgs(th)</u> ΔTJ	Gate Threshold Voltage Temperature Coefficient	$I_D = 250 \ \mu\text{A}$, Referenced to 25°C		-5		mV/°C
R _{DS(on)}	Static Drain–Source On–Resistance			3.1 4.0	3.5 5.6	mΩ
		$V_{GS} = 4.5 \text{ V}, \qquad I_D = 70 \text{ A}$		3.6	4.5	
I _{D(on)}	On–State Drain Current	$V_{GS} = 10 \text{ V}, \qquad V_{DS} = 10 \text{ V}$	60			Α
g fs	Forward Transconductance	$V_{DS} = 10 \text{ V}, \qquad I_D = 80 \text{ A}$		170		S
Dynamic	c Characteristics					
Ciss	Input Capacitance	$V_{DS} = 15 \text{ V}, \qquad V_{GS} = 0 \text{ V},$		10500		pF
Coss	Output Capacitance	f = 1.0 MHz		2700		pF
C _{rss}	Reverse Transfer Capacitance			1650		pF
Switchin	g Characteristics (Note 2)					
t _{D(on)}	Turn–On Delay Time	$V_{DD} = 15 V$, $I_D = 50 A$,		20	35	ns
t _r	Turn–On Rise Time	$V_{GS} = 4.5 \text{ V}, \qquad R_{GEN} = 10 \Omega$		185	225	ns
t _{D (off)}	Turn–Off Delay Time	$R_{GS} = 10 \Omega$		160	200	ns
t _f	Turn–Off Fall Time	1		200	240	ns
Q _g	Total Gate Charge	V _{DS} = 15 V,		120	170	nC
Q _{gs}	Gate–Source Charge	$I_{D} = 80 \text{ A}, V_{GS} = 5 \text{ V}$		27		nC
Q _{gd}	Gate–Drain Charge	1		48		nC
	ource Diode Characteristics	and Maximum Ratings	1			
	Maximum Continuous Drain–Source				80	А
Is I _{SM}	Maximum Pulsed Drain-Source Diode	х ў			300	A
V _{SD}	Drain–Source Diode Forward Voltage	, ,	1	1	1.3	V

1. Pulse Test: Pulse Width < 300μ s, Duty Cycle < 2.0%



FDP8030L/FDB8030L

FDP8030L/FDB8030L Rev C2(W)



FDP8030L/FDB8030L

FDP8030L/FDB8030L Rev C2(W)



TRADEMARKS

The following includes registered and unregistered trademarks and service marks, owned by Fairchild Semiconductor and/or its global subsidiaries, and is not intended to be an exhaustive list of all such trademarks

all such trauemarks.		
FPS™		Sync-Lock™
F-PFS™_		SYSTEM ^{®*}
FRFET®	PowerTrench [®]	CENEDAL
Global Power Resource SM	PowerXS™	GENERAL TinyBoost™
Green Bridge™	Programmable Active Droop [™]	TinyBuck™
Green FPS [™]	QFET®	TinyCalc™
Green FPS™ e-Series™	QS™	TinyLogic®
G <i>max</i> ™	Quiet Series [™]	TINYOPTO™
GTO™	RapidConfigure™	TinyPower™
IntelliMAX™	ТМ	TinyPWM™
ISOPLANAR™		TinyWire™
		TranSiC [®]
		TriFault Detect™
		TRUECURRENT®*
		μSerDes™
		μοσιρέα
		\mathcal{N}
		/ SerDes UHC [®]
		Ultra FRFET™
		UniFET™ VCX™
		VCX™ VisualMax™
OPTOLOGIC		
OPTOPLANAR [™]	SyncFET™	VoltagePlus™ XS™
		A.3
	FPS TM F-PFS TM FRFET [®] Global Power Resource SM Green Bridge TM Green FPS TM Green FPS TM e-Series TM Gmax TM GTO TM IntelliMAX TM ISOPLANAR TM	FPS TM U F-PFS TM PowerTrench [®] Global Power Resource SM PowerTrench [®] Green Bridge TM Programmable Active Droop TM Green FPS TM QFET [®] Green FPS TM QS TM Grawa TM Quiet Series TM GTO TM RapidConfigure TM IntelliMAX TM O ISOPLANAR TM Saving our world, 1mW/W/kW at a time TM Marking Small Speakers Sound Louder Saving our world, 1mW/W/kW at a time TM MICROCOUPLER TM SMART START TM MicroPak TM SPM [®] MicroPak TM SuperFET [®] MotionMax TM SuperSOT TM -3 MWSaver TM SuperSOT TM -6 OptOHIT TM SuperSOT TM -8

*Trademarks of System General Corporation, used under license by Fairchild Semiconductor.

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION, OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS. THESE SPECIFICATIONS DO NOT EXPAND THE TERMS OF FAIRCHILD'S WORLDWIDE TERMS AND CONDITIONS, SPECIFICALLY THE WARRANTY THEREIN, WHICH COVERS THESE PRODUCTS.

LIFE SUPPORT POLICY FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.

As used here in:

- Life support devices or systems are devices or systems which, (a) are 1 intended for surgical implant into the body or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury of the user.
- 2. A critical component in any component of a life support, device, or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

ANTI-COUNTERFEITING POLICY

Fairchild Semiconductor Corporation's Anti-Counterfeiting Policy. Fairchild's Anti-Counterfeiting Policy is also stated on our external website, www.Fairchildsemi.com, under Sales Support.

Counterfeiting of semiconductor parts is a growing problem in the industry. All manufactures of semiconductor products are experiencing counterfeiting of their parts. Customers who inadvertently purchase counterfeit parts experience many problems such as loss of brand reputation, substandard performance, failed application, and increased cost of production and manufacturing delays. Fairchild is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. Fairchild strongly encourages customers to purchase Fairchild parts either directly from Fairchild or from Authorized Fairchild Distributors who are listed by country on our web page cited above. Products customers buy either from Fairchild directly or from Authorized Fairchild Distributors are genuine parts, have full traceability, meet Fairchild's quality standards for handing and storage and provide access to Fairchild's full range of up-to-date technical and product information. Fairchild and our Authorized Distributors will stand behind all warranties and will appropriately address and warranty issues that may arise. Fairchild will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources. Fairchild is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors.

PRODUCT STATUS DEFINITIONS Definition of Terms

Datasheet Identification	Product Status	Definition	
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.	
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.	
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.	
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.	
Obsolete	Not In Production	Semiconductor. The datasheet is for reference information only.	

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at <u>www.onsemi.com/site/pdf/Patent-Marking.pdf</u>. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor has against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death ass

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor 19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com N. American Technical Support: 800–282–9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910

Japan Customer Focus Center Phone: 81-3-5817-1050 ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative

© Semiconductor Components Industries, LLC

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

ON Semiconductor: FDB8030L